

MOSFET Dual N-Ch 55V MOSFET

Manufacturers	<a href="#">Infineon Technologies Corporation</a>
Package/Case	TDSON-8
Product Type	Transistors
RoHS	Green
Lifecycle	



Images are for reference only

Please submit RFQ for IPG20N06S2L-35 or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

## General Description

IPG20N06S2L-35 is a specific model number for a power MOSFET transistor. It is manufactured by Infineon Technologies and belongs to the OptiMOS family.

## Features

Drain-Source voltage rating of 60V

Continuous Drain Current of 20A

Low on-state resistance (0.035ohm)

Fast switching speed

RoHS compliant

## Application

IRF3710ZPBF

FDP33N25

STP20NM60FP

FDP20N60NZ



**Related Products**



[IPP60R070CFD7](#)

Infineon Technologies Corporation  
TO-220-3



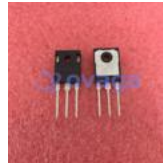
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